8-PIN PWM SWITCHER CONTROLLER IC PRELIMINARY DATASHEET

FEATURES

- 8-pin SOIC switching controller with HICCUP current limiting reduces diode power dissipation to less than 1% of normal operation
- Soft start capacitor allows for smooth output voltage ramp up
- On-board MOSFET driver
- Fastest transient response of any controller method. (0 to 100% Duty Cycle in 100nS)
- 1% internal voltage reference
- Internal undervoltage lockout protects MOSFET during start-up

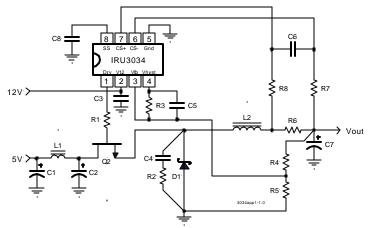
APPLICATIONS

- Dual supply low voltage processor applications, such as: P55C[™], CYRIX M2[™], POWER PC[™] and AMD K6[™]
- Simple 5V to 3.3V switcher for Pentium with AGP or Pentium II[™] applications

DESCRIPTION

The IRU3034 IC provides an 8-pin low cost switching controller with true short circuit protection all in a compact 8-pin surface mount packages, providing a low cost switching solution for dual supply processor applications that require switching regulator for the 3.3V supply such as the applications with AGP on board. Typically in these applications a dual supply regulator converts 5V to 3.3V for I/O supply and a jumper programmable supply of 1.25V to 3.5V for CORE supply . The IC uses an internal regulator generated from the 12V supply to power the controller as well as the 12V supply to drive the power MOSFET, allowing a low cost N-channel MOSFET to be used. The IC also includes an error comparator for fast transient response, a precise voltage reference for setting the output voltage as well as a direct drive of the MOSFET for the minimum part count.

TYPICAL APPLICATION



Typical application of IRU3034

Notes: P55C, Pentium II are trademarks of Intel Corp. K5 & K6 are trademarks of AMD corp. Cyrix 6X86L, M1, M2 are trademarks of Cyrix Corp. Power PC is trademark of IBM Corp.

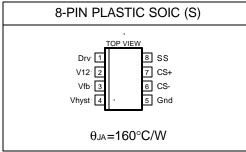
PACKAGE ORDER INFORMATION

TA (°C)	8-PIN PLASTIC SOIC (S)	
0 TO 70	IRU3034CS	

ABSOLUTE MAXIMUM RATINGS

V ₁₂ Supply Voltages	20V
F.B Pin Voltages	-0.3V to 5V
Storage Temperature Range	-65 TO 150° C
Operating Junction Temperature	0 TO 150°C

PACKAGE INFORMATION



ELECTRICAL SPECIFICATIONS

Unless otherwise specified the following specification applies over $V_{12} = 12V$, and $T_A = 0$ to 70°C. Low duty cycle pulse testing are used which keeps junction and case temperatures equal to the ambient temperature.

PARAMETER	SYM	TEST CONDITION	MIN	TYP	MAX	UNITS
F.B Voltage Initial Accuracy	Vfb	TJ =25°C	1.237	1.250	1.262	V
F.B Voltage Total Variation			1.225	1.250	1.275	V
F.B Voltage Line Regulation				0.2		%
F.B Input Bias Current	lfв	V _{FB} =1.25V	-1		+1	μA
Min On Time		VFB is sq wave with 300ns on		800		nS
		time and 2µS off time				
Min Off Time		VFB is sq wave with 300ns off		800		nS
		time and 2µS on time				
Vhyst pin output-HI		Isource =500µA, Vfb =1.5V	11			V
Vhyst pin output-LO		Isink =500µA, Vгв =1V			1	V
Supply Current	12SW	VFB =1V		10		mA
Maximum Duty Cycle	DMAX	V _{FB} =1V			100	%
Minimum Duty Cycle	DMIN	V _{FB} =1.5V	0			%
Gate Drive Rise/Fall Time	VGATE	Load=IRL3303		70		nS
C.L Threshold Current	lc∟	C.S+ , C.S- from 1.3V to 3.7V		20		μA
C.S Comp Common Mode	1	Vcs+ = Vcs-	0		4.5	V
Soft Start Current				10		μΑ

PIN DESCRIPTIONS

PIN #	PIN SYMBOL	PIN DESCRIPTION
3	Vfb	A resistor divider from this pin to the output of the switching regulator and ground sets the
		Core supply voltage.
6	C.S-	This pin is connected to the minus side of the external current sense resistor. An internal
		current source together with an external resistor in series with this pin programs the
		current limit threshold voltage. This voltage divided by the external current sense resistor
		sets the current limit threshold.
7	C.S+	This pin is connected to the plus side of the external current sense resistor. A resistor in
		series with this pin and a capacitor connected between this pin and pin 6 provides a high
		frequency filtering for the noise spikes of turn on and turn off switching.
5	Gnd	This pin is connected to the IC substrate and must be connected to the lowest potential
		in the system.
1	Drv	The PWM output of the switching controller. This pin is a totem pole drive that is con-
		nected to the gate of the power MOSFET. A resistor may be placed from this pin to the
		gate in order to reduce switching noise.
4	VHYST	A resistor and a 10pF capacitor is connected from this pin to the VFB1 pin to set the
		output ripple voltage for the switching regulator.
2	V12	This pin supplies the voltage to the PWM drive and hysterises circuitry and it is con-
		nected to the 12V supply. A 1 μ F, high frequency capacitor must be connected from this
		pin to ground to provide the peak current for charging and discharging of the MOSFET.
8	S.S	This pin provides the soft start for the regulator during power up. It also sets a long off
		time when the converter goes into current limiting, providing low duty cycle for the catch
		diode allowing it to survive during short circuit.

BLOCK DIAGRAM

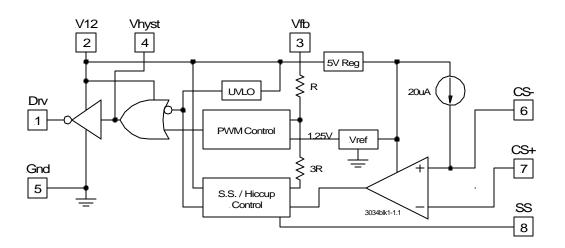


Figure 1 - Simplified block diagram of the IRU3034

TYPICAL APPLICATION

Pentium Core Supply Application (IRU3034 and IRU3033 Dual Layout) Low Cost 4-Bit VID

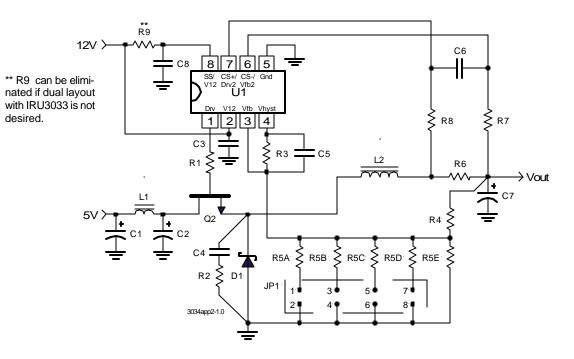


Figure 2 - Typical application of IRU3034 in a flexible motherboard with the 4 bit VID output voltage selection. This circuit is done using a dual layout with the IRU3033 part. The advantage of this circuit is that it uses a single jumper that programs the output voltage in 16 steps with 0.1V steps from 2V to 3.5V, designed for Intel P55, P54, AMD K5 & K6 as well as Cyrix M1 and M2 applications.

JP1	JP1	JP1	JP1	Outpu	ıt
1-2	3-4	5-6	7-8	Voltag	je
0	0	0	0	3.5	
0	0	0	1	3.4	
0	0	1	0	3.3	
0	0	1	1	3.2	
0	1	0	0	3.1	
0	1	0	1	3.0	
0	1	1	0	2.9	
0	1	1	1	2.8	
1	0	0	0	2.7	
1	0	0	1	2.6	
1	0	1	0	2.5	
1	0	1	1	2.4	
1	1	0	0	2.3	
1	1	0	1	2.2	
1	1	1	0	2.1	0 = Jumper block is installed.
1	1	1	1	2.0	1 = Jumper block is not installed.

Pentium Core Supply Application Parts List (IRU3034 and IRU3033 Dual Layout) Low Cost 4 Bit VID

Ref Desig Description		Qty	Part #	Manuf
U1	LDO/Switcher IC	1	IRU3034CS (8-pin SOIC)	IR
Q2	MOSFET	1	IRL3303 (TO-220)	IR
			IRL3103S (TO-263) (note 1)	
D1	Schottky Diode	1	MBR1045CT (TO-220)	
			MBRB1545CT (TO-263) (note1)	Motorola
L2	Inductor	1	Core: T50-18, L=4µH	Micro Metal
			Turns: 10T, 18 AWG	(core)
L1	Inductor	1	L=2µH	
R1	Resistor	1	22 ohm, 5%, SMT 1206 size	
R2	Resistor	1	10 ohm, 5%, SMT 1206 size	
R3	Resistor	1	324 kohm, 1%, SMT 0805 size	
R4A *	Resistor	1	806 ohm, 1%, SMT 0805 size	
R4B *	Resistor	1	90.9 kohm, 1%, SMT 0805 size	
R5A	Resistor	1	1.24 kohm, 1%, SMT 0805 size	
R5B	Resistor	1	2.49 kohm, 1%, SMT 0805 size	
R5C	Resistor	1	4.99 kohm, 1%, SMT 0805 size	
R5D	Resistor	1	10 kohm, 1%, SMT 0805 size	
R5E	Resistor	1	1.30 kohm, 1%, SMT 0805 size	
R6	Resistor	1	5 miliohm, 5%, 2W	
R7	Resistor	1	4.99 kohm, 1%, SMT 0805 size	
R8	Resistor	1	4.7 kohm, 5% for IRU3034, open for 3033	
R9	Resistor	1	Open for IRU3034, 10 ohm for IRU3033	
C1	Capacitor	1	6MV1500GX, 1500µF, 6.3V, Elect	
C2	Capacitor	1	6MV1500GX, 1500µF, 6.3V, Elect	Sanyo
C3	Capacitor	1	1µF, Ceramic, SMT 0805 size	
C4	Capacitor	1	470pF, Ceramic, SMT 0805 size	Sanyo
C5	Capacitor	1	10pF, Ceramic, SMT 0805 size	Sanyo
C7	Capacitor	4	6MV1500GX, 1500µF, 6.3V, Elect	Sanyo
C8	Capacitor	1	0.047µF for 3034 , 0.1µf for IRU3033	
C6	Capacitor	1	4700pF for IRU3034, open for IRU3033	
HS1	Heat Sink	1	For MOSFET, 577002	Aavid
HS2	Heat Sink	1	For Schottky Diode, 577002	Aavid

* R4 is a parallel combination of R4A and R4B.

Note 1: For the applications where it is desirable to eliminate the heat sink, the IRL3103S for Q2 and MBR1545CT for D2 in TO-263 packages with minimum of 1" square copper pad can be used.

TYPICAL APPLICATION

5V to 3.3V for Pentium Application with AGP or Pentium II Application without ATX power supply Switching mode Operation. (IRU3034 and IRU3033 Dual Layout)

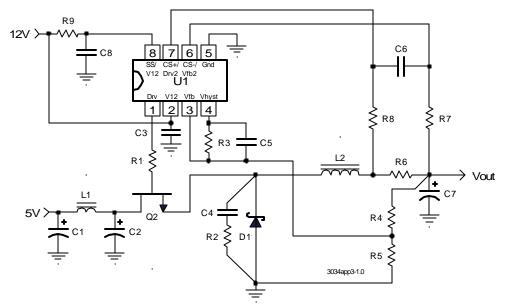


Figure 4 - The circuit in figure 4 is the application of the IRU3034 which is done using a dual layout with IRU3033 in a switching mode only. This circuit can be used to generate a low cost 5V to 3.3V for either Pentium application with AGP socket or in Pentium II applications where it is desirable to generate an accurate on board 3.3V supply.

Ref Desig Description Qty		Part #	Manuf	
U1	LDO/Switcher IC	1	IRU3034CS (8-pin SOIC)	IR
Q2	MOSFET	1	IRL3303 (TO-220)	IR
			IRL3103S (TO-263) (note 1)	
D1	Schottky Diode	1	MBR1045CT (TO-220)	
			MBRB1545CT (TO-263) (note1)	Motorola
L2	Inductor	1	Core: T50-18,L=4µH	Micro Metal
			Turns: 10T, 18 AWG	(core)
L1	Inductor	1	L=2µH	
R1	Resistor	1	22 ohm, 5%, SMT 1206 size	
R9	Resistor	1	open for IRU3034, 10 ohm for IRU3033	
R2	Resistor	1	10 ohm, 5%, SMT 1206 size	
R3	Resistor	1	249 kohm, 1%, SMT 0805 size	
R4	Resistor	1	1 kohm, 1%, SMT 0805 size	
R5	Resistor	1	576 ohm, 1%, SMT 0805 size	
R6	Resistor	1	5 miliohm, 5%, 2W	
R7	Resistor	1	4.99 kohm, 1%, SMT 0805 size	
R8	Resistor	1	4.7 kohm, 5% for IRU3034, open for IRU3033	
C1,2	Capacitor	2	6MV1500GX, 1500μF, 6.3V, Elect	Sanyo
C3	Capacitor	1	1µF, Ceramic, SMT 0805 size	
C4	Capacitor	1	470pF, Ceramic, SMT 0805 size	Sanyo
C5	Capacitor	1	10pF, Ceramic, SMT 0805 size	Sanyo
C6	Capacitor	1	4700pF for IRU3034, open for IRU3033	
C7	Capacitor	2	6MV1500GX, 1500µF, 6.3V, Elect	Sanyo
C8	Capacitor	1	0.047μF for IRU3034 , 0.1μF for 3033	
HS1	Heat Sink	1	For MOSFET, 577002	Aavid
HS2	Heat Sink	1	For Schottky Diode, 577002	Aavid

Note 1: For the applications where it is desirable to eliminate the heat sink, the IRL3103S for Q2 and MBR1545CT for D2 in TO-263 packages with minimum of 1" square copper pad can be used.

TYPICAL APPLICATION

5V to 3.3V with loss less short circuit protection (output UVLO detection)

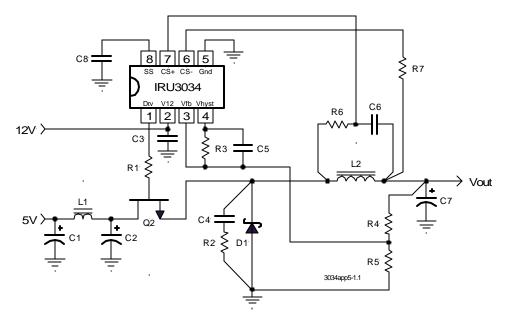


Figure 5- The circuit in figure 5 is designed to provide lossles output short detection by detecting the dc voltage across the inductor and shutting down the MOSFET and entering HICCUP mode. Note that the current limit point is a function of the inductor resistance and in this application with approximately 8 mil ohm resistance the peak C.L is set at 10A. See application note on how to set the current limiting threshold.

Ref Desig Description		Qty	Part #	Manuf
U1	Switcher IC	1	IRU3034CS (8-pin SOIC)	IR
Q2	MOSFET	1	IRL3303 (TO-263)	IR
D1	Schottky Diode	1	PBYR735 (Axial Thru Hole pkg)	
			PBYR1035B (SMT, T-263 pkg)	Motorola
L2	Inductor	1	Core: T50-18,L=4µH	Micro Metal
			Turns: 7T, 18 AWG	(core)
L1	Inductor	1	L=µH	
R1,2	Resistor	2	10 ohm, 5%, SMT	
R3	Resistor	1	182 kohm, 1%, SMT	
R4	Resistor	1	1 kohm, 1%, SMT	
R5	Resistor	1	576ohm, 1%, SMT	
R7	Resistor	1	3.83 kohm, 1%, SMT	
R6	Resistor	1	1 kohm, 1%, SMT	
C1	Capacitor	1	470μF, Elect	
C2	Capacitor	1	6MV1000GX, 1000µF, 6.3V, Elect	Sanyo
C3	Capacitor	1	1μF, Ceramic, SMT	
C5	Capacitor	1	10pF, Ceramic, SMT	Sanyo
C6	Capacitor	1	0.1µF	
C7	Capacitor	2	6MV1000GX, 1000µF, 6.3V, Elect	Sanyo
C8	Capacitor	1	0.047µF	

APPLICATION INFORMATION

Introduction

The IRU3034 device is an application specific product designed to provide an on-board switching supply for the new generation of microprocessors requiring separate Core and I/O supplies where the load current demand from the I/O supply requires this regulator to also be a switching regulator such as the motherboard applications with AGP slot or the Pentium II with on-board 5V to 3.3V converter. The IRU3034 provides an easy and low cost switching regulator solution for Vcore and 3.3V supplies with true short circuit protection.

Switching Controller Operation

The operation of the switching controller is as follows:

After the power is applied, the output drive pin, "Drv" goes to 100% duty cycle and the current in the inductor charges the output capacitor causing the output voltage to increase. When output reaches a pre-programmed set point the feedback pin "Vfb" exceeds 1.25V causing the output drive to switch low and the "Vhyst" pin to switch high which jumps the feedback pin higher than 1.25V resulting in a fixed output ripple which is given by the following equation:

dVo=(Rt/Rh)x11

Where:

Rt=Resistor connected from Vout to the Vfb pin of IRU3034

Rh=Resistor connected from Vfb pin to Vhyst pin.

For example, if Rt=1k and Rh=422k, then the output ripple is: dVo=(1/422)x11=26mV

The advantage of fixed output ripple is that when the output voltage changes from 2V to 3.5V, the ripple voltage remains the same which is important in meeting the Intel maximum tolerance specification.

Soft Start

The soft start capacitor must be selected such that during the start up when the output capacitors are charging up, the peak inductor current does not reach the current limit threshold. A minimum of 0.1μ F capacitor insures this for most applications. During start-up the soft start capacitor is charged up to approximately 6V keeping the output shutdown before an internal 10µA current source start discharging the soft start capacitor which slowly ramps up the inverting input of the PWM comparator, Vfb. This insures the output to ramp up at the same rate as the soft start cap thereby limiting the input current. For example, with 0.1µF and the 10µA internal current source the ramp up rate is $(\Delta V / \Delta t)=I/Css = 10/0.1=100V/Sec \text{ or }0.1V/mSec$. Assuming that the output capacitance is 6000μ F, the peak input current will be:

lin(pk)=Css*(Δ V/ Δ t)=6000 μ F*(0.1V/mSec)=0.6A

The soft start capacitor also provides a delay in the turn on of the output which is given by:

Td=CsS*K Where K=30 ms/ μ F For example for CsS=0.1 μ F, Td=0.1* 30=3 ms

Switcher Current Limit Protection

The IRU3034 uses an external current sensing resistor and compares the voltage drop across it to a programmed voltage which is set externally via a resistor (RcL) placed between the "CS-" terminal of the IC and Vout. Once the voltage across the sense resistor exceeds the threshold, the soft start capacitor pulls up to 12V, pulling up the inverting pin of the error comparator higher than noninverting which causes the external MOSFET to shut off. At this point the C.S comparator changes its state and pulls the soft start capacitor to Vcc which is 12V and shutting the PWM drive. After the output drive is turned off, an internal 10µA current source slowly discharges the soft start capacitor to approximately 5.7V, before the output starts to turn back on causing a long delay before the MOSFET turns back on. This delay causes the catch diode to cool off between the current limit cycles allowing the converter to survive a short circuit condition. An example is given below as how to select the current limiting components. Assuming the desired current limit point is set to be 20A and the current sense resistor Rs=5m Ω , then the current limit programming resistor, RcL is calculated as:

Vcs=IcL*Rs=20*0.005=0.1V RcL=Vcs/Ib=(0.1V)/(20μA)=5kΩ

Where: b=20 μ A is the internal current source of the IRU3034

The peak power dissipated in the C.S. resistor is:

Ppk=(IcL^2)*Rs=20^2*0.005=2W

However, the average power dissipated is much lower than 2W due to the long off time caused by the hiccup circuit of 3034. The average power is in fact the short circuit period divided by the short circuit period plus the off time or "hiccup" period. For example, if the short circuit lasts for TSC=100 μ Sec before the IRU3034 enters hiccup, the average power is calculated as:

Pave=0.5*Ppk*DSC Where: DSC=TSC/THCP THCP=CSS*M Where M=200 ms/ μ F & CSS, is the soft start capacitor

For example: for CSS=0.1 μ F & TSC=500 μ Sec=0.5mS THCP=0.1* 200=20ms Pave=0.5*2*(0.5/20)=25mW Without "hiccup" technique, the power dissipation of the resistor is 2W.

Switcher Output Voltage Setting

The output voltage can be set using the following equations:

Assuming, Vo=3.38V and the selected output ripple is \approx 1.3%(44mV) of the output voltage, a set of equations are derived that selects the resistor divider and the hysterises resistor.

Assuming, Rt=1k Ω , 1% Rh=(11*Rt)/ Δ Vo Where: Rt=Top resistor of the resistor divider Rh=Hysterises resistor connected between pins 3 and 4 of the IRU3034 Δ Vo=Selected output ripple (typically 1% to 2% of output voltage) Assuming, ΔVo=44mV Rh=(11*1000)/0.044=250kΩ Select Rh=249kΩ, 1%

The bottom resistor of the divider is then calculated using the following equations:

Rb=Rt/X Where: Rb=Bottom resistor of the divider X=[(Vo + (Δ Vo/2))/Vref] - 1 Vref=1.25 V typical X=[(3.38+ (0.044/2))/1.25] - 1 = 1.72 Rb=1000/1.72=580\Omega Select Rb=576 Ω , 1%

Frequency Calculation

The IRU3034 frequency of operation is calculated using the following formula:

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\label{eq:Fs} \begin{split} & \mathsf{Fs} = [(\mathsf{Vo}^*(1\text{-}\mathsf{D})^*\mathsf{ESR})]/(\mathsf{L}^*\Delta\mathsf{Vo}) \quad (\mathsf{MHz}) \\ & \mathsf{Where:} \\ & \mathsf{Vo} = \mathsf{Output} \ \mathsf{voltage} \quad (\mathsf{V}) \\ & \mathsf{D} = \mathsf{Duty} \ \mathsf{cycle} \\ & \mathsf{ESR} = \mathsf{Output} \ \mathsf{capacitor} \ \mathsf{ESR} \quad (\mathsf{V}) \\ & \mathsf{L} = \mathsf{Output} \ \mathsf{inductance} \quad (\mu\mathsf{H}) \\ & \Delta\mathsf{Vo} = \mathsf{Output} \ \mathsf{ripple} \ \mathsf{voltage} \quad (\mathsf{V}) \end{split}
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For our example: $D\approx(Vo + Vf)/Vin$ Where, Vf=Forward voltage drop of the Schottky diode D=(3.38 + 0.5)/5=0.78

The ESR=18m $\Omega\,$ for 2 of the Sanyo 1500µF, 6MV1500GX caps. If L=3.5µH then, Fs is calculated as follows:

Fs=[(3.38*(1-0.78)*0.018)]/(3.5*0.044)= 0.087 Mhz = 87kHz